

HMC618ALP3E

/dd2

N/C Vdd1 N/C Data Sheet

IC MMIC AMP LNA ADJ IDS 16-QFN

Manufacturers	Analog Devices, Inc	N/C 1 12 N/C
Package/Case	QFN-16	RFIN 2 N/C 3 10 GND
Product Type	RF Amplifiers	N/C 4 9 N/C 5 6 7 8
RoHS	Pb-free Halide free	S S S S S S S S S S S S S S S S S S S
Lifecycle		Images are for reference only

Please submit RFQ for HMC618ALP3E or Email to us: sales@ovaga.com We will contact you in 12 hours.

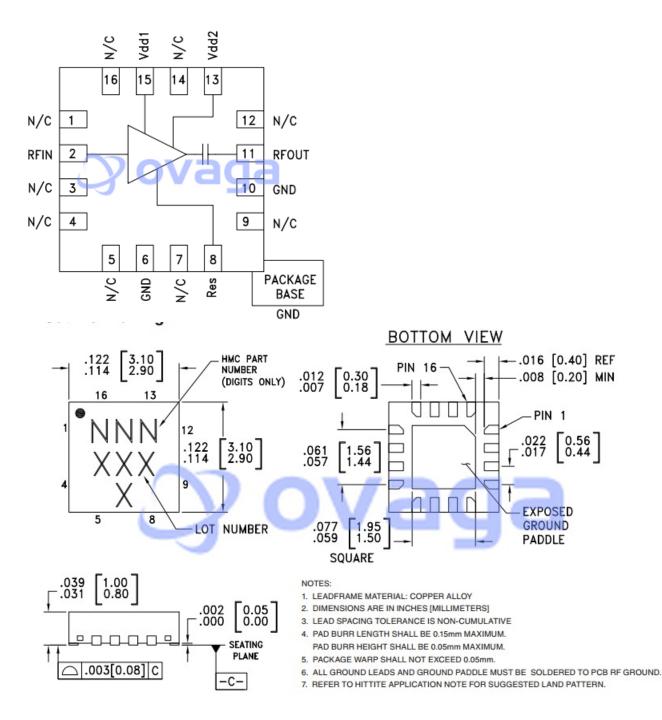
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General Description

The HMC618ALP3E is a GaAs pHEMT MMIC Low Noise Amplifier that is ideal for Cellular/3G and LTE/WiMAX/4G basestation front-end receivers operating between 1.2 - 2.2 GHz. The amplifier has been optimized to provide 0.75 dB noise figure, 19 dB gain and +36 dBm output IP3 from a single supply of +5V. Input and output return losses are excellent and the LNA requires minimal external matching and bias decoupling components. The HMC618ALP3E shares the same package and pinout with the HMC617LP3E 0.55 - 1.2 GHz LNA. The HMC618ALP3E can be biased with +3V to +5V and features an externally adjustable supply current which allows the designer to tailor the linearity performance of the LNA for each application. The HMC618ALP3E offers improved noise figure versus the previously released HMC375LP3(E) and the HMC382LP3(E).

Features	Application
Noise Figure: 0.75 dB	Cellular/3G and LTE/WiMAX/4G
Gain: 19 dB	BTS & Infrastructure
OIP3: 36 dBm	Repeaters and Femto Cells
Single Supply: $+3V$ to $+5V$	Public Safety Radio
50 Ohm Matched Input/Output	

16 Lead 3x3mm SMT Package: 9 mm²



Related Products



Analog Devices, Inc

HMC3653LP3BE



QFN-12

HMC253AQS24 Analog Devices, Inc

24-SSOP (0.154, 3.90mm Width)



HMC441LP3E

Analog Devices, Inc QFN-16

HMC948LP3E

Analog Devices, Inc LP3



HMC358MS8GE

Analog Devices, Inc MSOP-8



<u>HMC490</u>

Analog Devices, Inc SMD



HMC453ST89E Analog Devices, Inc

ST89E



HMC463LP5E

Analog Devices, Inc QFN-32